

## Electronic structure of $3d^1$ configuration vanadium oxides studied by hard x-ray photoemission spectroscopy

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We investigate the electronic structure of the  $3d^1$  configuration vanadium oxides  $\text{VO}_2$ ,  $\text{SrVO}_3$  and  $\text{CaVO}_3$  using hard x-ray (7937 eV) photoemission spectroscopy (HX-PES) at undulator beam line BL29XUL in SPring-8.

$\text{VO}_2/\text{TiO}_2:\text{Nb}$  thin films exhibit a metal-insulator transition (MIT) as a function of temperature at  $T_{MI} = 295$  K. The HX-PES valence band spectra clearly show the opening of a gap at  $E_F$  accompanying the MIT. Spectral changes in the V  $2p$  and V  $1s$  core levels were also observed as a function of temperature. In addition,  $3d^1$  configuration metals  $\text{SrVO}_3$  and  $\text{CaVO}_3$  are typical materials whose valence band spectra are compared with the dynamical mean-field theory. The  $d$ -bandwidth can be controlled easily by the V-O-V bond angle, i.e., the  $d$ -bandwidth  $W$  of  $\text{SrVO}_3$  is larger than that of  $\text{CaVO}_3$ . The V  $2p$  and  $1s$  core level HX-PES of  $\text{SrVO}_3$  and  $\text{CaVO}_3$  show clear additional well-screened features. These features originate from bulk screening by coherent band at  $E_F$  as observed in other  $3d$  transition metal oxides. Comparison between  $\text{SrVO}_3$  and  $\text{CaVO}_3$  in HX-PES shows a small increase of the intensity of these well-screened features in  $\text{SrVO}_3$ . The spectra are nicely reproduced by a cluster model calculation, indicating a difference of the parameter  $V^*$  for the interaction strength between the central V  $3d$  orbitals and the coherent band.